

## SPI/QPI PSRAM

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### Specifications

- **Single Supply Voltage**
  - VDD=2.7 to 3.6V
- **Interface:** SPI/QPI with SDR mode
- **Performance:** Clock rate up to
  - 133MHz for 32 Bytes Wrapped Burst operation at VDD=3.0V+/-10%
  - 109MHz for 32 Bytes Wrapped Burst operation at VDD=3.3V+/-10%
  - 84MHz for Linear Burst operation
- **Organization:** 64Mb, 8M x 8bits
- **Addressable Bit Range:** A[22:0]
- **Page Size:** 1024 bytes
- **Refresh:** Self-managed
- **Operating Temperature Range:**
  - Tc = -40°C to +85°C (standard range)
  - Tc = -40°C to +105°C (extended range)
- **Maximum Standby Current**
  - 350μA @ 105°C
  - 250μA @ 85°C
  - 140μA @ 25°C

### Features

- **50Ω Output Drive Strength LVCMOS**
- **Linear Burst** (continuous) or **32 Bytes Wrapped Burst** via toggle command.
- **Linear Burst** is supported up to 84MHz and can cross page boundary as long as tCEM is met.
- **Software reset**

## Table of Contents

### 1 Table of Contents

|      |                                                                   |    |
|------|-------------------------------------------------------------------|----|
| 1    | Table of Contents .....                                           | 2  |
| 2    | Introduction .....                                                | 4  |
| 3    | Package Information .....                                         | 4  |
| 3.1  | Package Types : SOP / USON (SN, ZR) , not to scale, Top view..... | 4  |
| 4    | Package Outline Drawing.....                                      | 5  |
| 4.1  | SOP-8L(150), package code SN .....                                | 5  |
| 4.2  | USON-8L 3x2mm, package code ZR.....                               | 6  |
| 5    | Ordering Information .....                                        | 7  |
| 6    | Signal Table .....                                                | 8  |
| 7    | Power-Up Initialization .....                                     | 8  |
| 8    | Interface Description .....                                       | 9  |
| 8.1  | Address Space .....                                               | 9  |
| 8.2  | Page Size .....                                                   | 9  |
| 8.3  | Drive Strength .....                                              | 9  |
| 8.4  | Power-on Status.....                                              | 9  |
| 8.5  | Command/Address Latching Truth Table .....                        | 9  |
| 8.6  | Command Termination .....                                         | 10 |
| 9    | Wrap Boundary Toggle Operation.....                               | 11 |
| 10   | SPI Mode Operations .....                                         | 12 |
| 10.1 | SPI Read Operations.....                                          | 12 |
| 10.2 | SPI Write Operations.....                                         | 14 |
| 10.3 | SPI Quad Mode Enable Operation .....                              | 15 |
| 10.4 | SPI Read ID Operation.....                                        | 15 |
| 11   | QPI Mode Operations .....                                         | 16 |
| 11.1 | QPI Read Operation .....                                          | 16 |
| 11.2 | QPI Write Operation(s) .....                                      | 17 |
| 11.3 | QPI Quad Mode Exit operation.....                                 | 17 |
| 12   | Reset Operation .....                                             | 18 |

|      |                                       |    |
|------|---------------------------------------|----|
| 13   | Input/Output Timing .....             | 19 |
| 14   | Electrical Specifications: .....      | 20 |
| 14.1 | Absolute Maximum Ratings .....        | 20 |
| 14.2 | Pin Capacitance .....                 | 20 |
| 14.3 | Decoupling Capacitor Requirement..... | 21 |
| 14.4 | Operating Conditions .....            | 21 |
| 14.5 | DC Characteristics .....              | 22 |
| 14.6 | AC Characteristics .....              | 23 |
| 15   | Change Log.....                       | 24 |

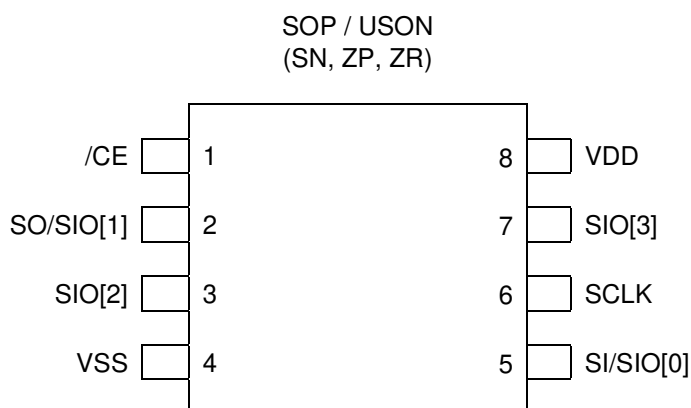
## 2 Introduction

This Pseudo-SRAM device features a high speed, low pin count interface. It has 4 SDR I/O pins and operates in SPI(serial peripheral interface) or QPI (quad peripheral interface) mode with frequencies up to 133 MHz. The data input (A/DQ) to the memory relies on clock (CLK) to latch all instructions, addresses and data. It is most suitable for low-power and low cost portable applications. It incorporates a seamless self-managed refresh mechanism. Hence it does not require the support of DRAM refresh from system host. The self-refresh feature is a special design to maximize performance of memory read operation.

## 3 Package Information

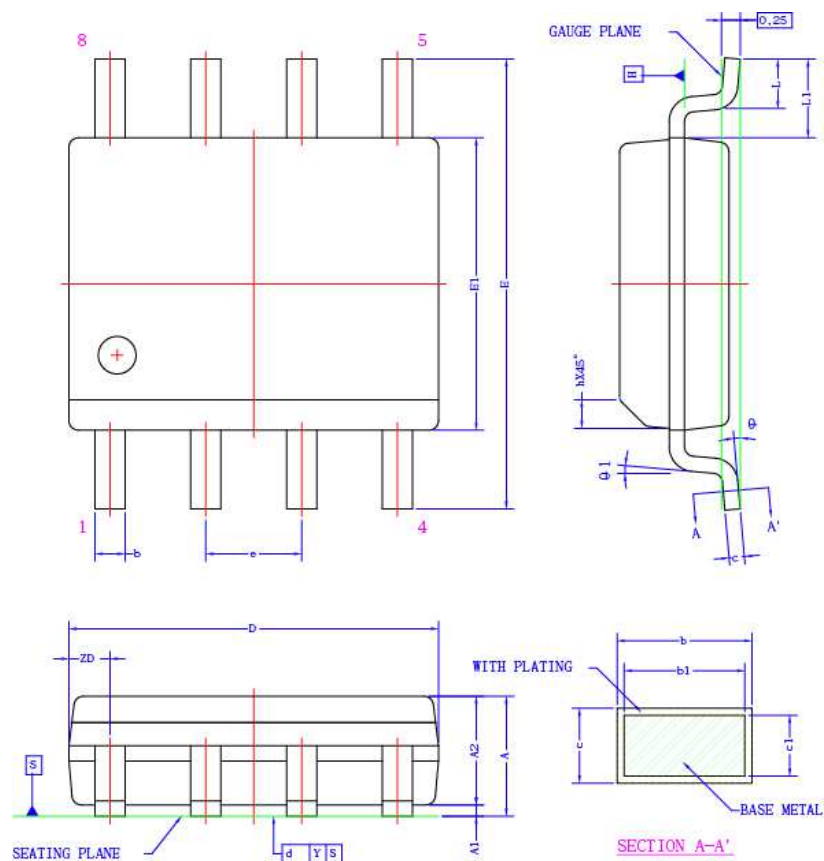
The APS6404L-3SQR is available in standard package including 8-lead SOP-8L(150) and advanced package including 8-lead USON-8L 3x2mm.

### 3.1 Package Types : SOP / USON (SN, ZR) , not to scale, Top view



## 4 Package Outline Drawing

### 4.1 SOP-8L(150), package code SN

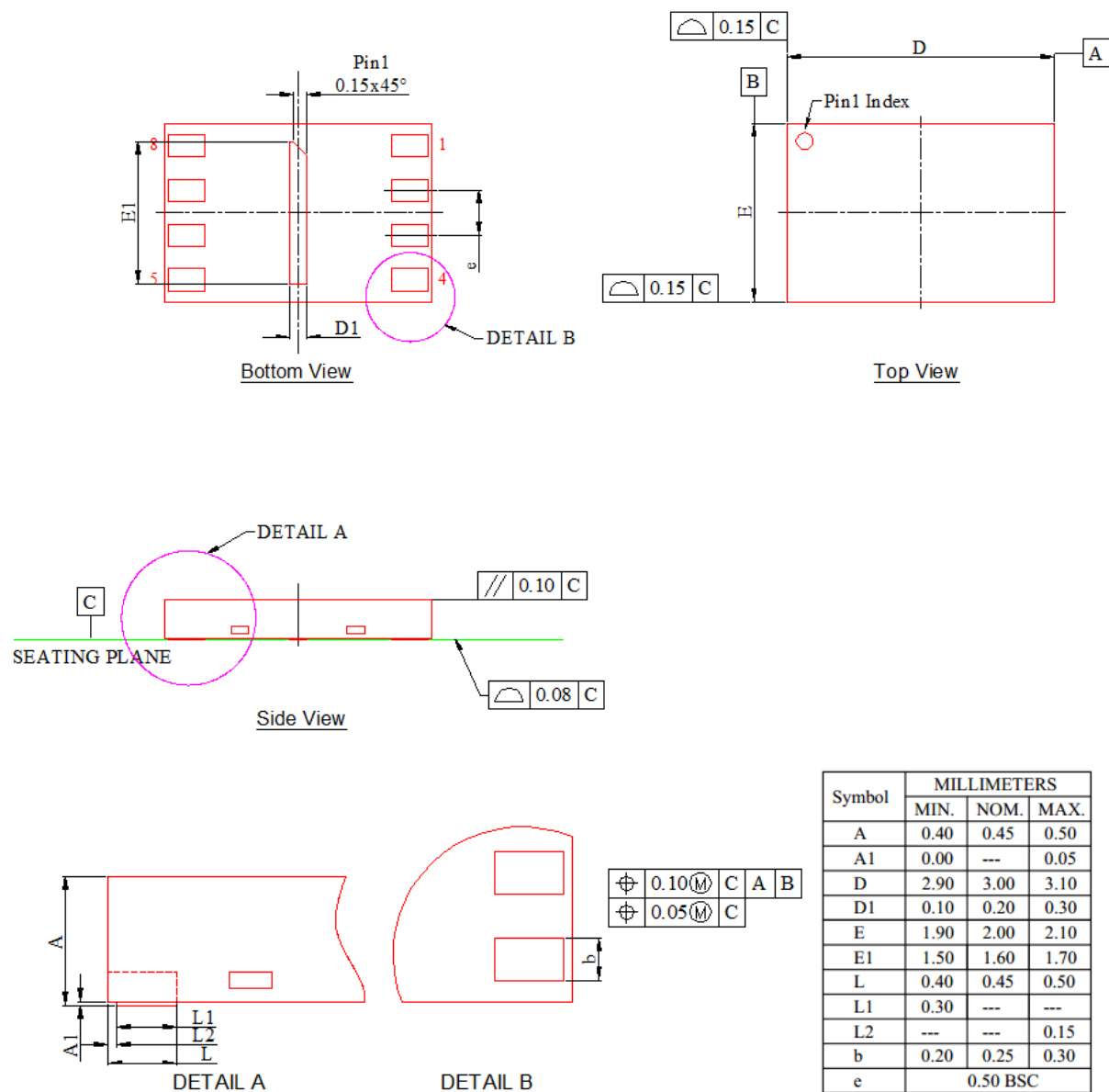


| SYMBOL | DIMENSION (MM) |      |      | DIMENSION (MIL) |      |      |
|--------|----------------|------|------|-----------------|------|------|
|        | MIN.           | NOM. | MAX. | MIN.            | NOM. | MAX. |
| A      | 1.35           | 1.60 | 1.75 | 53              | 63   | 69   |
| A1     | 0.10           | 0.15 | 0.25 | 4               | 6    | 10   |
| A2     | 1.35           | 1.45 | 1.55 | 53              | 57   | 61   |
| b      | 0.31           | —    | 0.51 | 12              | —    | 20   |
| b1     | 0.28           | 0.40 | 0.48 | 11              | 16   | 19   |
| c      | 0.17           | —    | 0.25 | 7               | —    | 10   |
| c1     | 0.17           | 0.20 | 0.23 | 7               | 8    | 9    |
| D      | 4.80           | 4.90 | 5.00 | 189             | 193  | 197  |
| E      | 6.00 BSC       |      |      | 236 BSC         |      |      |
| E1     | 3.80           | 3.90 | 4.00 | 150             | 154  | 157  |
| e      | 1.27 BSC       |      |      | 50 BSC          |      |      |
| L      | 0.40           | 0.66 | 1.27 | 16              | 26   | 50   |
| L1     | 1.05 REF       |      |      | 41 REF          |      |      |
| ZD     | 0.55 REF       |      |      | 22 REF          |      |      |
| h      | 0.25           | 0.38 | 0.50 | 10              | 15   | 20   |
| Y      | —              | —    | 0.10 | —               | —    | 4    |
| θ      | 0°             | —    | 8°   | 0°              | —    | 8°   |
| θ1     | 0°             | —    | —    | 0°              | —    | —    |

#### NOTE :

1. REFER TO JEDEC STD: MS-012 AA.
2. DIMENSION "D" DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURRS. MOLD FLASH, PROTRUSION AND GATE BURRS SHALL NOT EXCEED 0.15mm PER SIDE.  
DIMENSION "E1" DOES NOT INCLUDE INTERLEAD MOLD FLASH OR PROTRUSION. INTERLEAD MOLD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25mm PER SIDE.  
'D' AND 'E1' DIMENSIONS ARE DETERMINED AT DATUM H.
3. DIMENSION "b" DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.10mm TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION.  
THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

## 4.2 USON-8L 3x2mm, package code ZR



**NOTE:**

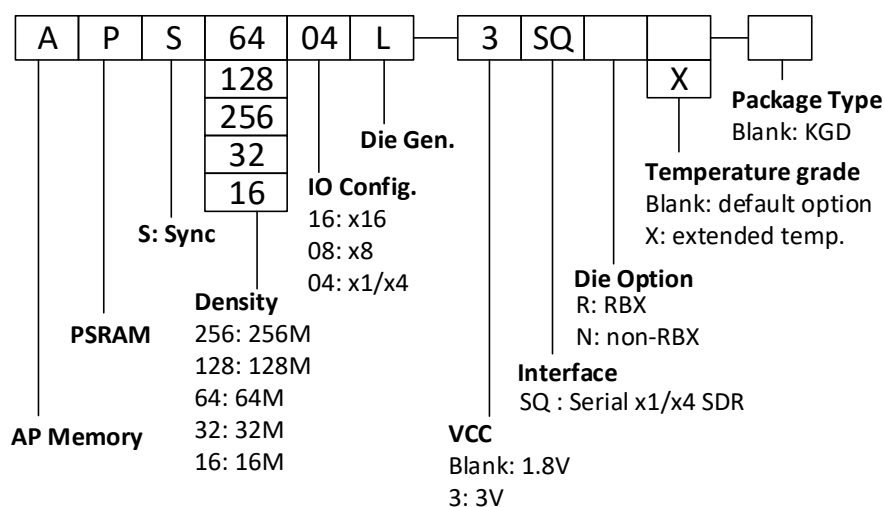
1. Scale 1:4
2. ALL DIMENSIONS AND TOLERANCES TAKE REFERENCE TO JEDEC MO-229
3. DIMENSION "b" APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.15MM AND 0.30MM FROM THE TERMINAL TIP. IF THE TERMINAL HAS OPTIONAL RADIUS ON THE OTHER END OF THE TERMINAL, THE DIMENSION B SHOULD NOT BE MEASURED IN THAT RADIUS AREA.

## 5 Ordering Information

**Table 1: Ordering Information**

| Part Number       | Temperature Range    | Max Frequency | Note   |
|-------------------|----------------------|---------------|--------|
| APS6404L-3SQR-ZR  | Tc = -25°C to +85°C  | 133 MHz*      | USON-8 |
| APS6404L-3SQR-SN  | Tc = -40°C to +85°C  | 133 MHz*      | SOP-8  |
| APS6404L-3SQRX-SN | Tc = -40°C to +105°C | 133 MHz*      | SOP-8  |

Note \*: 133MHz for 32 Bytes Wrapped Burst operation at VDD=3.0V+/-10%  
 109MHz for 32 Bytes Wrapped Burst operation at VDD=3.3V+/-10%  
 84MHz for Linear Burst operation with RBX(row boundary crossing)



## 6 Signal Table

All signals are listed in Table 2.

**Table 2: Signals Table**

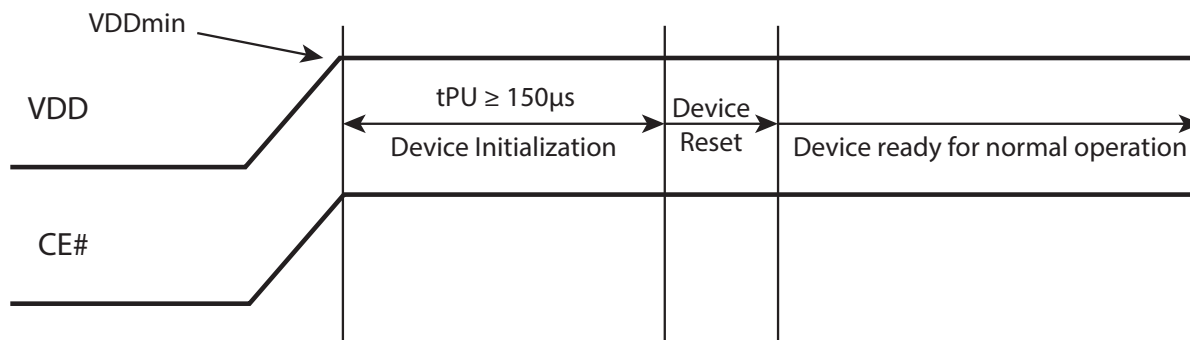
| Symbol    | Type   | SPI Mode Function                                             |        | QPI Mode Function | Comments |
|-----------|--------|---------------------------------------------------------------|--------|-------------------|----------|
| VDD       | Power  | Core supply                                                   |        |                   |          |
| VSS       | Ground | Core supply ground                                            |        |                   |          |
| CE#       | Input  | Chip select, active low. When CE#=1, chip is in standby state |        |                   |          |
| CLK       | Input  | Clock Signal                                                  |        |                   |          |
| SI/SIO[0] | IO     | Serial Input                                                  | IO[0]* | IO[0]             |          |
| SO/SIO[1] | IO     | Serial Output                                                 | IO[1]* | IO[1]             |          |
| SIO[2]    | IO     | --                                                            | IO[2]* | IO[2]             |          |
| SIO[3]    | IO     | --                                                            | IO[3]* | IO[3]             |          |

Note \*: SPI Quad mode

## 7 Power-Up Initialization

SPI/QPI products include an on-chip voltage sensor used to start the self-initialization process. When VDD reaches a stable level at or above minimum VDD, the device will require 150μs and user-issued RESET Operation (see section 12) to complete its self-initialization process. From the beginning of power ramp to the end of the 150μs period, CLK should remain LOW, CE# should remain HIGH (track VDD within 200mV) and SI/SO/SIO[3:0] should remain LOW.

After the 150μs period the device is ready for normal operation.



**Figure 1. Power-Up Initialization Timing**

## 8 Interface Description

### 8.1 Address Space

SPI/QPI PSRAM device is byte-addressable. 64M device is addressed with A[22:0].

### 8.2 Page Size

Page size is 1K (CA[9:0]). Default burst setting is Linear Bursting that crosses page boundary in a continuous manner. Note however that burst operations which cross page boundary have a lower max input clock frequency of 84MHz, and it can cross page boundary one time only in a burst. Optionally the device can also be set to wrap 32 (CA[4:0]) via the Wrap Boundary Toggle command and is not allowed to cross page boundary in this configuration.

### 8.3 Drive Strength

The device powers up in 50Ω.

### 8.4 Power-on Status

The device powers up in SPI Mode. It is required to have CE# high before beginning any operations.

### 8.5 Command/Address Latching Truth Table

The device recognizes the following commands specified by the various input methods.

|                                    |      | SPI Mode (QE=0) |      |            |     |           | QPI Mode (QE=1) |      |            |     |           |
|------------------------------------|------|-----------------|------|------------|-----|-----------|-----------------|------|------------|-----|-----------|
| Command                            | Code | Cmd             | Addr | Wait Cycle | DIO | Max Freq. | Cmd             | Addr | Wait Cycle | DIO | Max Freq. |
| Read                               | 'h03 | S               | S    | 0          | S   | 33        | N/A             |      |            |     |           |
| Fast Read                          | 'h0B | S               | S    | 8          | S   | 133/84*   | Q               | Q    | 4          | Q   | 66        |
| Fast Read Quad                     | 'hEB | S               | Q    | 6          | Q   | 133/84*   | Q               | Q    | 6          | Q   | 133/84*   |
| Write                              | 'h02 | S               | S    | 0          | S   | 133/84*   | Q               | Q    | 0          | Q   | 133/84*   |
| Quad Write                         | 'h38 | S               | Q    | 0          | Q   | 133/84*   | same as 'h02    |      |            |     |           |
| Enter Quad Mode                    | 'h35 | S               | -    | -          | -   | 133       | N/A             |      |            |     |           |
| Exit Quad Mode                     | 'hF5 | N/A             |      |            |     |           | Q               | -    | -          | -   | 133       |
| Reset Enable                       | 'h66 | S               | -    | -          | -   | 133       | Q               | -    | -          | -   | 133       |
| Reset                              | 'h99 | S               | -    | -          | -   | 133       | Q               | -    | -          | -   | 133       |
| Wrap Boundary Toggle               | 'hC0 | S               | -    | -          | -   | 133       | Q               | -    | -          | -   | 133       |
| Read ID                            | 'h9F | S               | S    | 0          | S   | 33        | N/A             |      |            |     |           |
| Remark: S = Serial IO, Q = Quad IO |      |                 |      |            |     |           |                 |      |            |     |           |

Note \*: **Max Freq.** would be 133MHz at VDD=3.0V+/-10% and 109MHz at VDD= 3.3V+/-10%) under Wrap32 operation; **Max Freq.** would be 84MHz under Linear Burst operation. Please refer Section 9 for Wrap32 and Linear Burst operation.

## 8.6 Command Termination

All Reads & Writes must be completed by raising CE# high immediately afterwards in order to terminate the active command and set the device into standby. Not doing so will block internal refresh operations and cause memory failure.

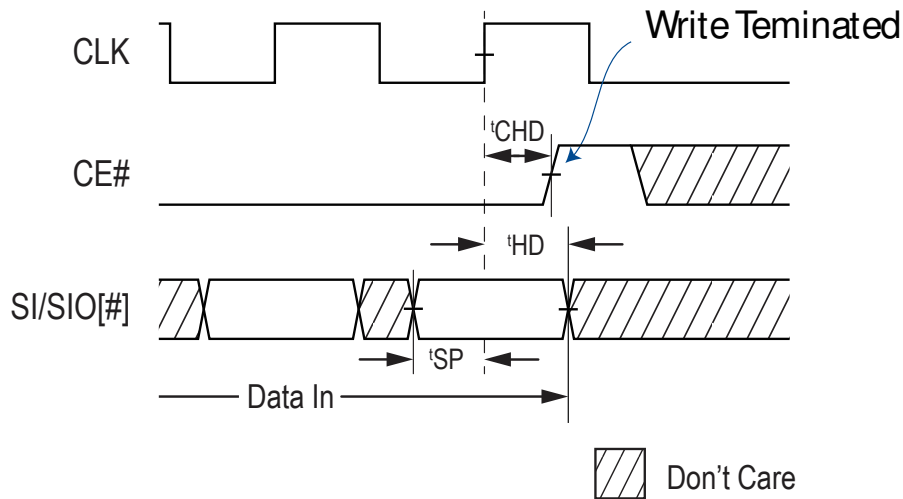


Figure 2: Write Command Termination

For a memory controller to correctly latch the last piece of data prior to read termination, it is recommended to provide a longer CE# hold time ( $t_{CHD} > t_{ACLK} + t_{CLK}$ ) for a sufficient data window.

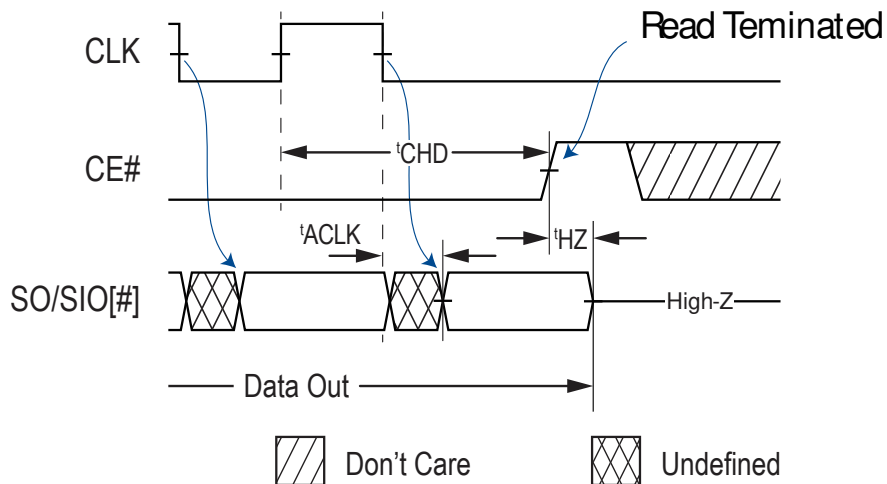


Figure 3: Read Command Termination

## 9 Wrap Boundary Toggle Operation

The Wrap Boundary Toggle Operation switches the device's wrapped boundary between Linear Burst which crosses the 1K page boundary (CA[9:0]) and Wrap 32 (CA[4:0]) bytes. Default setting is Linear Burst.

Linear Burst allows the device to burst through page boundary. Page boundary crossing is invisible to the memory controller and limited to a lower max CLK frequency of 84MHz.

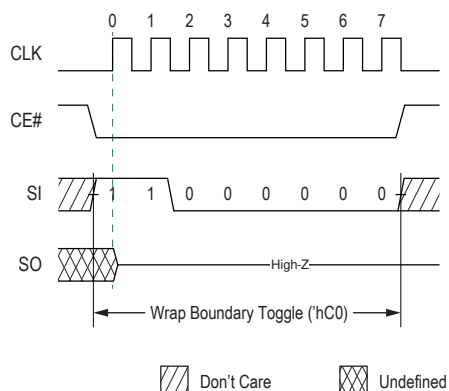


Figure 4: SPI Wrap Boundary Toggle 'hC0

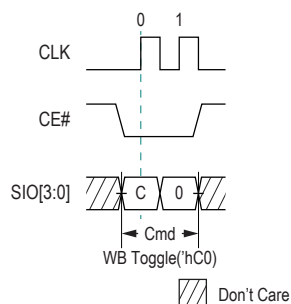


Figure 5: QPI Wrap Boundary Toggle 'hC0

Table 3: Wrapped Length:

| Default        | CMDs ('h03,'h0B,'hEB,'h02,'h38) |                                 |
|----------------|---------------------------------|---------------------------------|
| Wrapped Length | Page Boundary Crossing enabled  | Page Boundary Crossing disabled |
| Linear burst   | Linear 1K cross page boundary   | Wrap 1K                         |
| Wrap 32        | Wrap 32                         | Wrap 32                         |

## 10 SPI Mode Operations

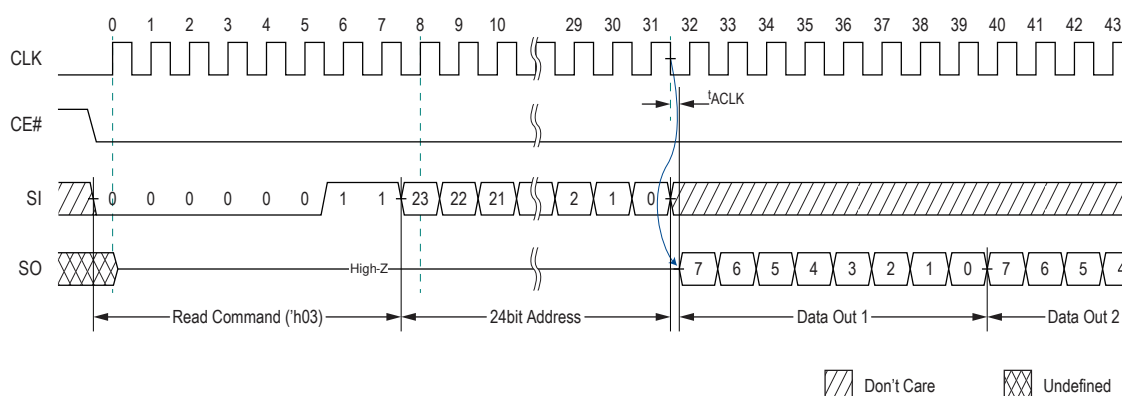
The device powers up into SPI mode by default but can also be switched into QPI mode.

### 10.1 SPI Read Operations

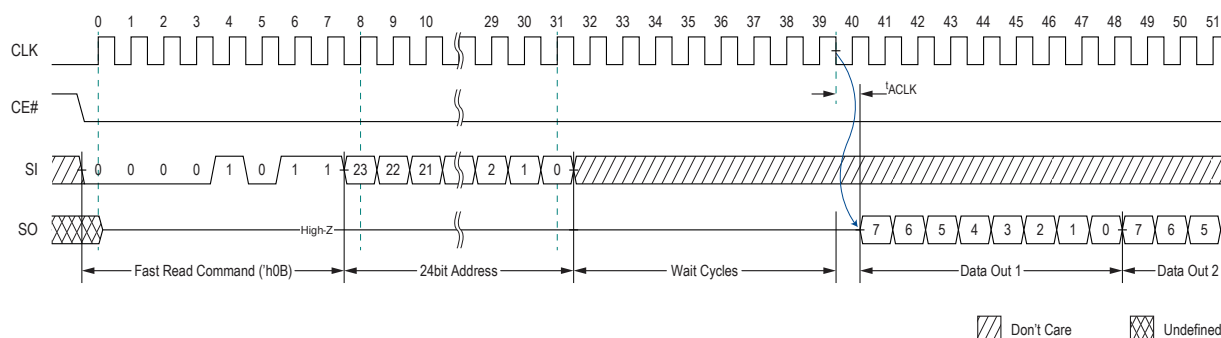
For all reads, data will be available  $t_{\text{ACLK}}$  after the falling edge of CLK.

SPI Reads can be done in three ways with Linear Burst or 32 Bytes Wrapped Burst:

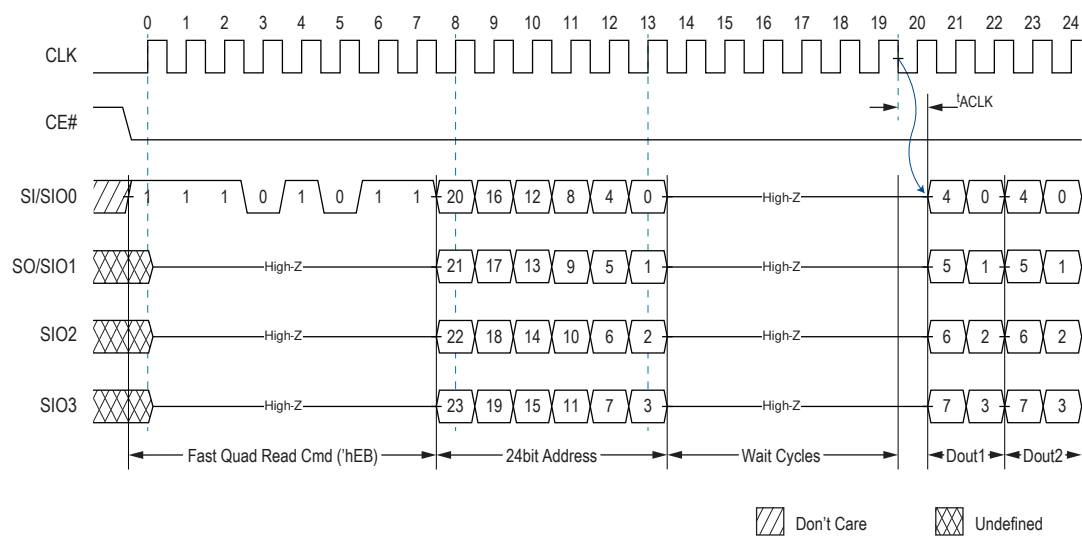
1. 'h03: Serial CMD, Serial Addr/IO, slow frequency
2. 'h0B: Serial CMD, Serial Addr/IO, fast frequency
3. 'hEB: Serial CMD, Quad Addr/IO, fast frequency



**Figure 6: SPI Read 'h03 (max freq 33MHz)**



**Figure 7: SPI Fast Read 'h0B (max freq 133 MHz)**



**Figure 8: SPI Fast Quad Read 'hEB (max freq 133 MHz)**

## 10.2 SPI Write Operations

SPI write command can be input as 'h02 or 'h38.

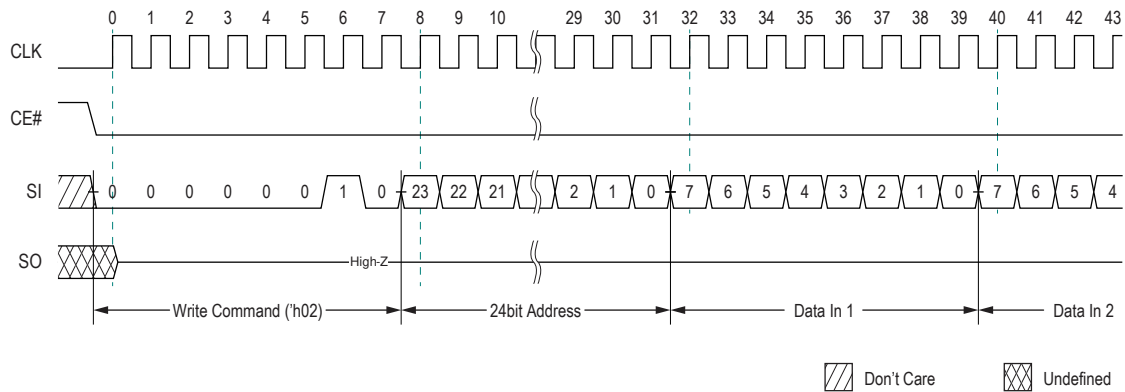


Figure 9: SPI Write 'h02

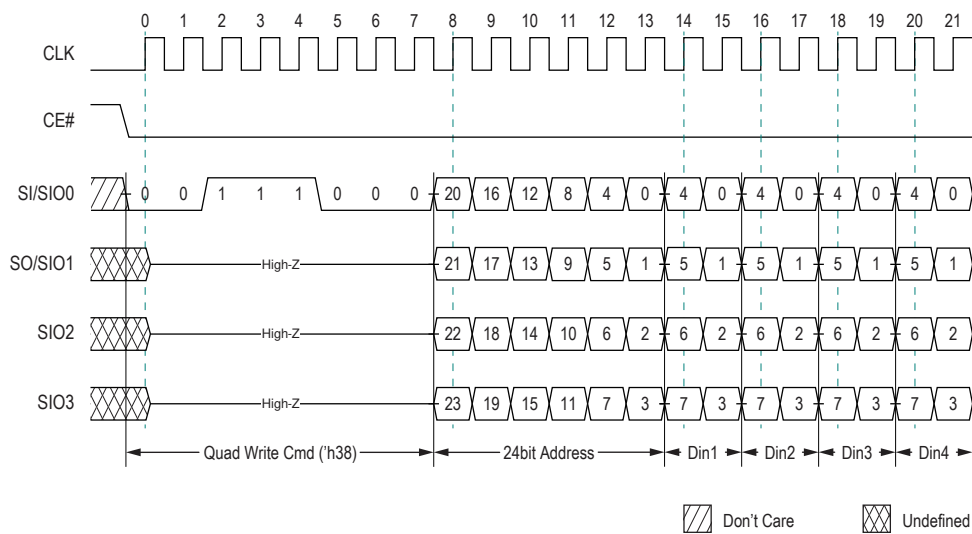


Figure 10: SPI Quad Write 'h38

### 10.3 SPI Quad Mode Enable Operation

This command switches the device into quad IO mode.

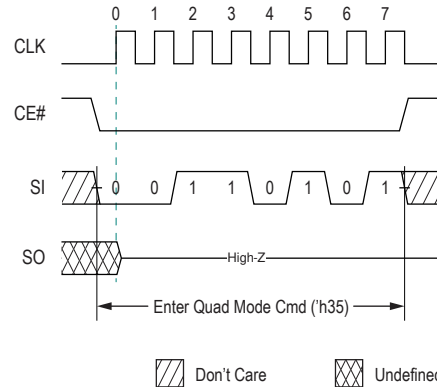


Figure 11: Quad Mode Enable 'h35 (available only in SPI mode)

### 10.4 SPI Read ID Operation

This command is similar to Fast Read, but without the wait cycles and the device outputs EID value instead of data.

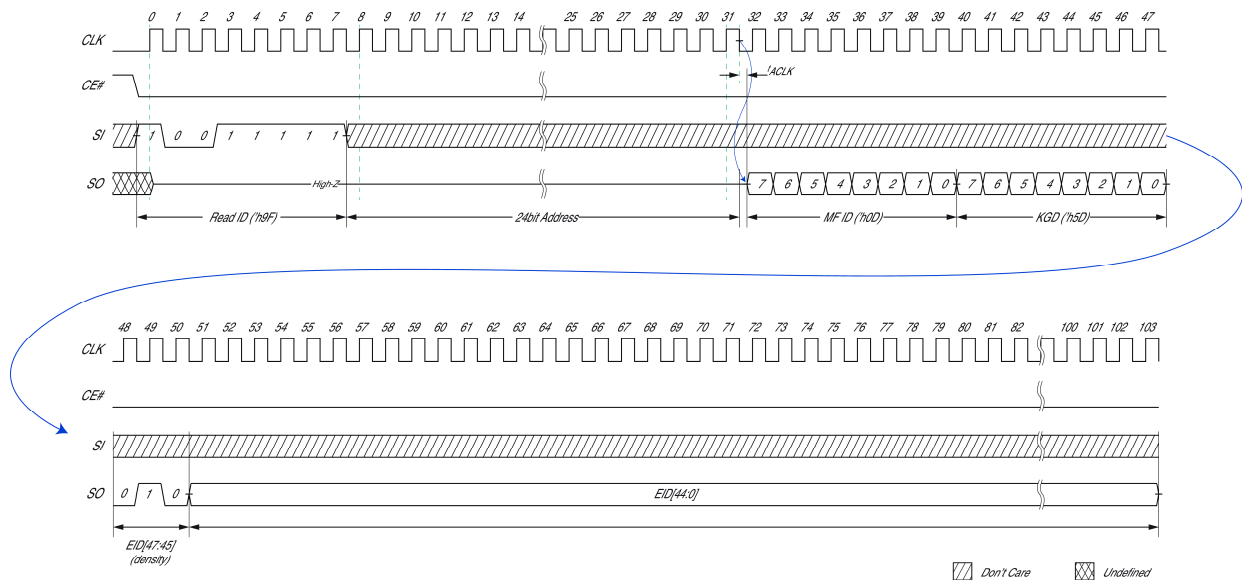


Figure 12: SPI Read ID 'h9F (available only in SPI mode)

Table 4: Known Good Die (KGD)

| KGD[7:0]    | Known Good Die |
|-------------|----------------|
| 'b0101_0101 | FAIL           |
| 'b0101_1101 | PASS           |

\*Note: Default is FAIL die, and only mark PASS after all tests passed.

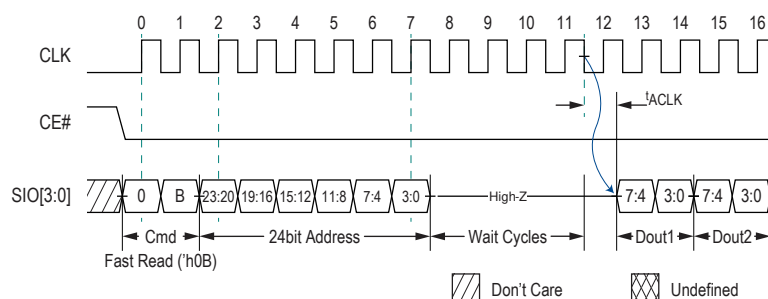
## 11 QPI Mode Operations

### 11.1 QPI Read Operation

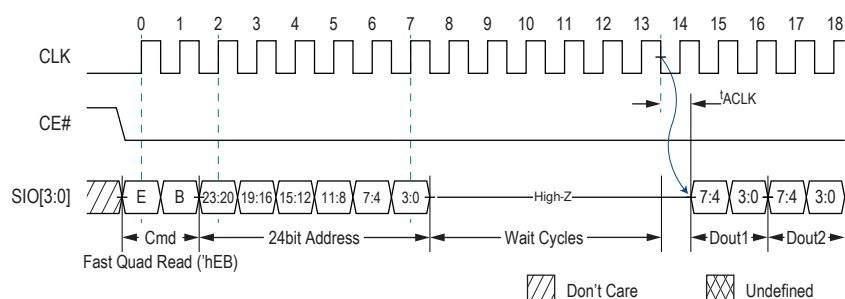
For all reads, data will be available  $t_{\text{ACLK}}$  after the falling edge of CLK.

QPI Reads can be done in one of two ways with Linear Burst or 32 Bytes Wrapped Burst:

1. 'h0B: Quad CMD, Quad Addr/IO, slow frequency
2. 'hEB: Quad CMD, Quad Addr/IO, fast frequency



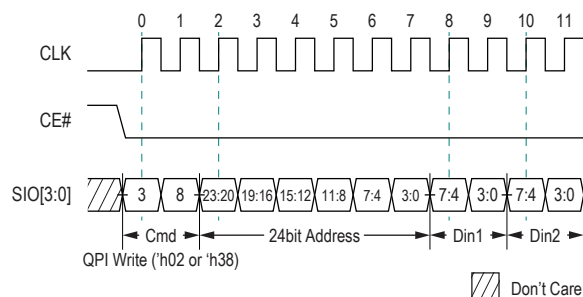
**Figure 13: QPI Fast Read 'h0B (max freq 66 MHz)**



**Figure 14: QPI Fast Quad Read 'hEB (max freq 133 MHz)**

## 11.2 QPI Write Operation(s)

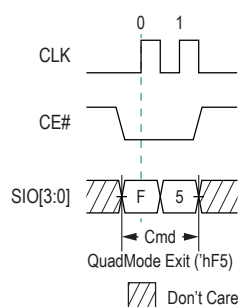
QPI write command can be input as 'h02 or 'h38.



**Figure 15: QPI Write 'h02 or 'h38**

## 11.3 QPI Quad Mode Exit operation

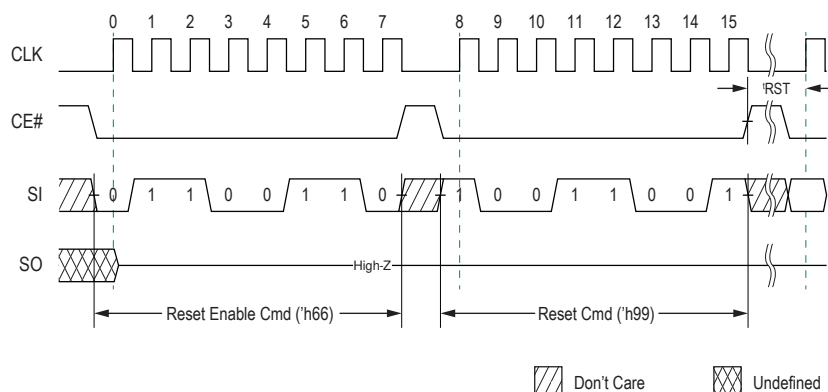
This command will switch the device back into serial IO mode.



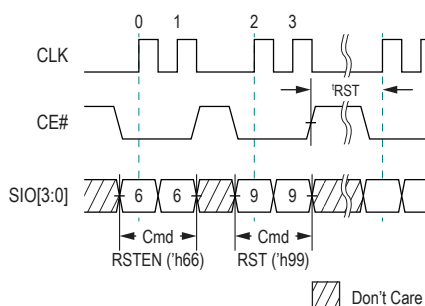
**Figure 16: Quad Mode Exit 'hF5 (only available in QPI mode)**

## 12 Reset Operation

The Reset operation is used as a system (software) reset that puts the device in SPI standby mode which is also the default mode after power-up. This operation consists of two commands: Reset-Enable (RSTEN) and Reset (RST).



**Figure 17: SPI Reset**



**Figure 18: QPI Reset**

Reset command has to immediately follow the Reset-Enable command in order for the reset operation to take effect. Any command other than the Reset command after the Reset-Enable command will cause the device to exit Reset-Enable state and abandon reset operation.

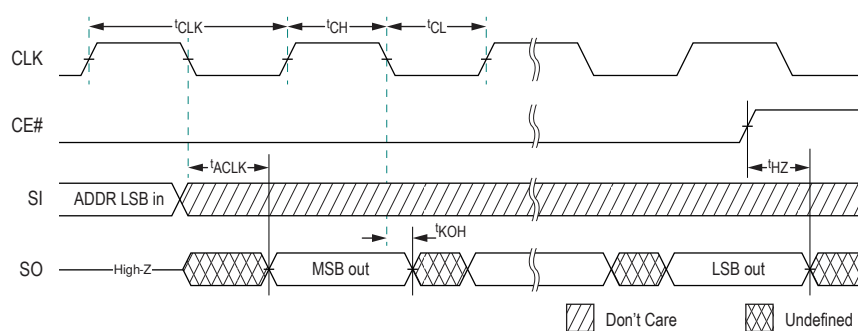
The timing diagram illustrates the relationship between the clock (CLK), chip enable (CE#), serial input (SI), and serial output (SO) signals. Key timing parameters are labeled:

- $t_{CH}$ : Clock high pulse width.
- $t_{CL}$ : Clock low pulse width.
- $t_{CLK}$ : Clock period.
- $t_{KHKL}$ : Clock high-to-low and low-to-high transition times.
- $t_{CSP}$ : Setup time for CE# before CLK.
- $t_{CEM}$ : Hold time for CE# after CLK.
- $t_{CHD}$ : Delay from CE# to the output.
- $t_{CPH}$ : Clock-to-output delay.
- $t_{HD}$ : Input data hold time before CLK.
- $t_{SP}$ : Setup time for SI before CLK.
- MSB in**: Most Significant Bit input.
- LSB in**: Least Significant Bit input.
- High-Z**: Output state when not driving.

Legend:

- Don't Care
- Undefined

**Figure 19: Input Timing**



### Figure 20: Output Timing

## 14 Electrical Specifications:

### 14.1 Absolute Maximum Ratings

**Table 5: Absolute Maximum Ratings**

| Parameter                                                | Symbol    | Rating               | Unit | Notes |
|----------------------------------------------------------|-----------|----------------------|------|-------|
| Voltage to any ball except $V_{DD}$ relative to $V_{SS}$ | VT        | -0.4 to $V_{DD}+0.4$ | V    |       |
| Voltage on $V_{DD}$ supply relative to $V_{SS}$          | $V_{DD}$  | -0.4 to +4.0         | V    | 2     |
| Storage Temperature                                      | $T_{STG}$ | -55 to +150          | °C   | 1     |

Notes 1: Storage temperature refers to the case surface temperature on the center/top side of the PSRAM.

Notes 2: During voltage transitions, all pins may overshoot to -0.5V or  $V_{CC}+0.5V$  for period up to 20ns.

Caution:

Exposing the device to stress above those listed in Absolute Maximum Ratings could cause permanent damage. The device is not meant to be operated under conditions outside the limits described in the operational section of this specification. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

### 14.2 Pin Capacitance

**Table 6: Package Pin Capacitance**

| Parameter              | Symbol | Min | Max | Unit | Notes   |
|------------------------|--------|-----|-----|------|---------|
| Input Pin Capacitance  | CIN    |     | 6   | pF   | VIN=0V  |
| Output Pin Capacitance | COUT   |     | 8   | pF   | VOUT=0V |

Note 1: spec'd at 25°C.

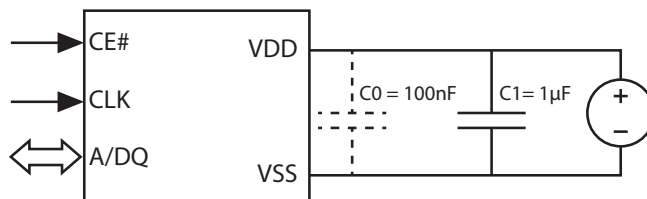
**Table 7: Load Capacitance**

| Parameter        | Symbol | Min | Max | Unit | Notes |
|------------------|--------|-----|-----|------|-------|
| Load Capacitance | $C_L$  |     | 15  | pF   |       |

Note 1: System  $C_L$  for the use of package

### 14.3 Decoupling Capacitor Requirement

It is required to have a decoupling capacitor on VDD pin for IO switchings and psram internal transient events. A low ESR 1 $\mu$ F ceramic cap is recommended. To minimize parasitic inductance, place the cap as close to VDD pin as possible. An optional 0.1 $\mu$ F can further improve high frequency transient response.



### 14.4 Operating Conditions

Table 8: Operating Characteristics

| Parameter                        | Min       | Max | Unit | Notes            |
|----------------------------------|-----------|-----|------|------------------|
| Operating Temperature (extended) | -40       | 105 | °C   | 1                |
| Operating Temperature (standard) | -40(-25*) | 85  | °C   | *USON package ZR |

Note 1: spec'd temp range of -40 to 105°C is only characterized; test condition will be -32 to 105°C.

## 14.5 DC Characteristics

Table 9: DC Characteristics

| Symbol                 | Parameter                                     | Min                  | Max                  | Unit | Notes |
|------------------------|-----------------------------------------------|----------------------|----------------------|------|-------|
| V <sub>DD</sub>        | Supply Voltage                                | 2.7                  | 3.6                  | V    |       |
| V <sub>IH</sub>        | Input high voltage                            | V <sub>DD</sub> -0.4 | V <sub>DD</sub> +0.2 | V    |       |
| V <sub>IL</sub>        | Input low voltage                             | -0.2                 | 0.4                  | V    |       |
| V <sub>OH</sub>        | Output high voltage (I <sub>OH</sub> =-0.2mA) | 0.8 V <sub>DD</sub>  |                      | V    |       |
| V <sub>OL</sub>        | Output low voltage (I <sub>OL</sub> =+0.2mA)  |                      | 0.2 V <sub>DD</sub>  | V    |       |
| I <sub>LI</sub>        | Input leakage current                         |                      | 1                    | μA   |       |
| I <sub>LO</sub>        | Output leakage current                        |                      | 1                    | μA   |       |
| I <sub>CC</sub>        | Read/Write                                    |                      | 7                    | mA   | 1,2   |
| ISB <sub>EXT</sub>     | Standby current (extended temp)               |                      | 350                  | μA   | 3     |
| ISB <sub>STD</sub>     | Standby current (standard temp)               |                      | 250                  | μA   | 3     |
| ISB <sub>STDroom</sub> | Standby current (standard room temp)          |                      | 140                  | μA   | 3,4   |

Note 1: Output load current not included.

2. **Typical I<sub>CC</sub> 5.5mA at 133MHz**

3. Standby current is measured when CLK is in DC low state.

4. **Typical ISB<sub>STDroom</sub> 100uA**

## 14.6 AC Characteristics

**Table 10: READ/WRITE Timing**

| Symbol          | Parameter                                     | Min  | Max  | Unit                  | Notes                    |
|-----------------|-----------------------------------------------|------|------|-----------------------|--------------------------|
| $t_{CLK}$       | CLK period - SPI Read ('h03)                  | 30.3 |      | ns                    | 33MHz                    |
|                 | CLK period - QPI Read ('h0B)                  | 15.1 |      |                       | 66MHz                    |
|                 | CLK period - all other operations PKG 3V      | 7.5  |      |                       | 133MHz <sup>*1,2,3</sup> |
|                 | CLK period - all other operations PKG 3.3V    | 9.17 |      |                       | 109MHz <sup>*2,3</sup>   |
|                 | CLK period - all other operations             | 11.9 |      |                       | 84MHz <sup>*1</sup>      |
| $t_{CH}/t_{CL}$ | Clock high/low width                          | 0.45 | 0.55 | $t_{CLK}(\text{min})$ |                          |
| $t_{KHL}$       | CLK rise or fall time                         |      | 1.5  | ns                    | 4                        |
| $t_{CPH}$       | CE# HIGH between subsequent burst operations  | 18   |      | ns                    |                          |
| $t_{CEM}$       | CE# low pulse width                           |      | 4    | $\mu\text{s}$         | Extended grade           |
|                 |                                               |      | 8    |                       | Standard grade           |
| $t_{CSP}$       | CE# setup time to CLK rising edge PKG         | 2.5  |      | ns                    |                          |
| $t_{CHD}$       | CE# hold time from CLK rising edge PKG        | 3.0  |      | ns                    | 2                        |
| $t_{SP}$        | Setup time to active CLK edge                 | 2    |      | ns                    |                          |
| $t_{HD}$        | Hold time from active CLK edge                | 2    |      | ns                    |                          |
| $t_{HZ}$        | Chip disable to DQ output high-Z              |      | 5.5  | ns                    |                          |
| $t_{ACLK}$      | CLK to output delay                           | 2    | 5.5  | ns                    |                          |
| $t_{KOH}$       | Data hold time from clock falling edge        | 1.5  |      | ns                    |                          |
| $t_{RST}$       | Time between end of RST CMD to next valid CMD | 50   |      | ns                    |                          |

- Note
- 1: Only Linear Burst allows page boundary crossing. Frequency limits are therefore 133MHz (PKG VDD= 3.0V+-10%), 109MHz(PKG VDD= 3.3V+-10%) max for Wrap 32 Bytes, and 84MHz for Linear Burst commands cross page boundary
  - 2: System max  $C_L$  15pF for the use of package.
  - 3: For operating frequencies >84MHz, it is highly recommended to utilize CLK falling edge to sample read data or align sampling clock via data pattern tuning (refer to JEDEC JESD84-B50 for an example).
  - 4: Measured from 20% to 80% of VDD

## 15 Change Log

| Version | Date         | Description                                                                                                                                                                      |
|---------|--------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 0.1     | Jul 13, 2017 | Initial Version                                                                                                                                                                  |
| 1.1     | Juy 25, 2017 | Revised package code and ordering information                                                                                                                                    |
| 1.2     | Aug 24, 2017 | Corrected package code; Added system max $C_L$ for the use of package & related tCK and tCHD                                                                                     |
| 1.3     | Sep 04, 2017 | Added ISBstdroom                                                                                                                                                                 |
| 1.5     | Oct 30, 2017 | Enabled QPI Read 'h0B support; changed Min/Max absolute voltage, Vil_min and Vih_max,; defined tCEM for different temperature grade; corrected speed typo. Added USON package ZR |
| 1.6     | Nov 13, 2017 | Modified spec of ICC & ISB                                                                                                                                                       |
| 1.7     | Mar 19, 2018 | Revised part# of RBX. Temperature -40C                                                                                                                                           |
| 1.8     | Jan 07, 2019 | Remove WSON and updated POD of USON, add tRST                                                                                                                                    |
| 1.9     | Sep 05, 2019 | Updated Figure 12, Table 7 and Table 9; Added table for Change Log; updated section 8.5 and 14.6; added section 14.3                                                             |
| 2.0a    | Oct 02, 2019 | Updated header, page 1 and Table 1                                                                                                                                               |
| 2.1     | Oct 25, 2019 | Revised the typo in page 12 and 16; update Table 3, Figure 17 and Figure 18                                                                                                      |
| 2.2     | Nov 21, 2019 | Update Table 2, Figure 10 and Figure 15                                                                                                                                          |
| 2.3     | Apr 30, 2020 | Modify VDD's description of Table 2                                                                                                                                              |